

Part Number: XRNI04W-R

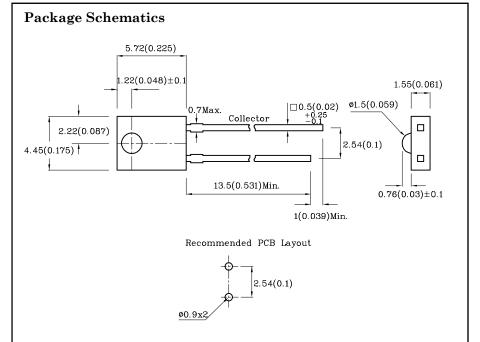
Phototransistor

Features

- Radial / Through hole package
- Reliable & robust
- Low power consumption
- Water clear lens
- Halogen-free
- RoHS Compliant







Notes

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
- 3. Specifications are subject to change without notice.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Condiction
VBR CEO	Collector-to-Emitter Breakdown Voltage	30	-	-	V	$\begin{split} I_{c} &= 100 \mu A \\ E_{e} &= 0 mW/cm^{2} \end{split}$
VBR ECO	Emitter-to-Collector Breakdown Voltage	5	-	-	V	$\begin{split} I_{\scriptscriptstyle E} &= 100 \mu A \\ E_{\scriptscriptstyle e} &= 0 mW/cm^2 \end{split}$
VCE(SAT)	Collector-to-Emitter Saturation Voltage	-	-	0.8	V	$\begin{split} &I_{C}=2mA\\ &E_{e}=20mW/cm^{2} \end{split}$
Iceo	Collector Dark Current	-	-	100	nA	$\begin{aligned} V_{\mathrm{CE}} &= 10 V \\ E_{\mathrm{e}} &= 0 \mathrm{mW/cm^2} \end{aligned}$
$ m t_r$	Rise Time (10% to 90%)	-	15	-	μs	V_{CE} = 5V I_{C} = 1mA R_{L} = 1K Ω
$\mathbf{t_f}$	Fall Time (90% to 10%)	-	15	-	μs	
I(ON)	On State Collector Current	0.35	0.8	-	mA	$V_{\rm CE}$ = 5V $E_{\rm e}$ = 1 mW/cm ² λ = 940nm
$\lambda_{0.1}$	Range of Spectral Bandwidth	420	-	1120	nm	-
$\lambda_{ m p}$	Wavelength of Peak Sensitivity	-	940	=	nm	-

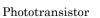
Absolute Maximum Ratings at TA=25°C

Parameter	Maximum Ratings		
Collector-to-Emitter Voltage	30V		
Emitter-to-Collector Voltage	5V		
Power Dissipation at (or below) 25°C Free Air Temperature	100mW		
Operating / Storage Temperature Range	-40 ~ +85°C		
Lead Solder Temperature (>5mm for 5sec)	260°C		

A Relative Humidity between 40% and 60% is recommended in

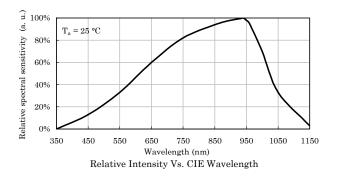
ESD-protected work areas to reduce static build up during assembly process (Reference JEDEC/JESD625-A and JEDEC/J-STD-033)

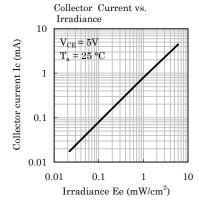
Nov 27,2025 XDSA4439 V7 Layout: Maggie L.

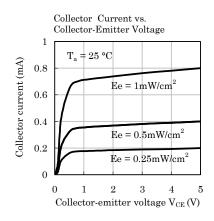


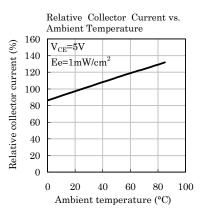


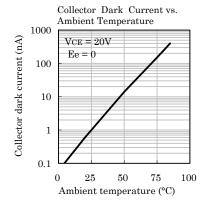


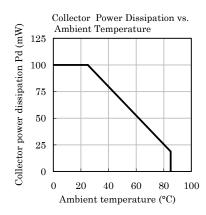


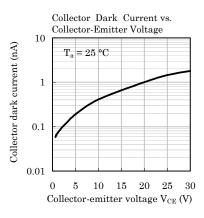






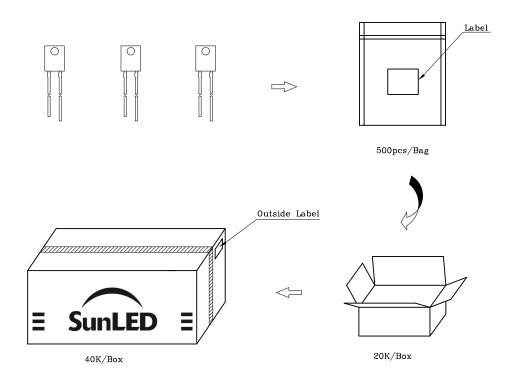


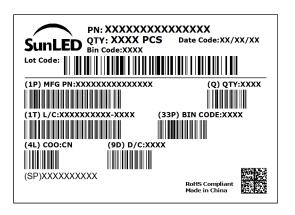




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PACKING & LABEL SPECIFICATIONS





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Nov 27,2025